NSN 5961-01-398-9066

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-398-9066

Overall Length:
1.114 inches
Overall Height:
1.0475 inches
Overall Width:
0.095 inches
Response Time:
8.0 microseconds
Voltage Rating In Volts Per Characteristic:
50.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter to collector, base open and 0.3 collector to
emitter saturation voltage
Current Rating Per Characteristic:
3.00 milliamperes collector cutoff current, dc, emitter open and 25.00 nanoamperes repetitive peak forward current peak
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Precious Material And Location:
Finish gold
Precious Material:
Gold
Test Data Document:
11263-65008g drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0